



Ultrahigh-Speed Switching Applications

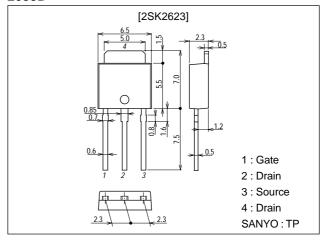
Features

- · Low ON-resistance.
- · Low Qg.

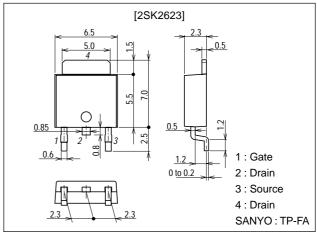
Package Dimensions

unit:mm

2083B



2092B



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Specifications

Absolute Maximum Ratings at Ta = 25°C

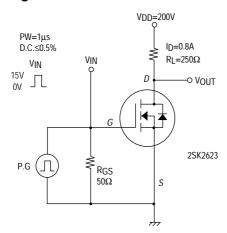
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		600	V
Gate-to-Source Voltage	V _{GSS}		±30	V
Drain Current (DC)	I _D		1.5	Α
Drain Current (Pulse)	I _{DP}		6	Α
Allowable Power Dissipation	D-		1.0	W
	PD	Tc=25°C	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

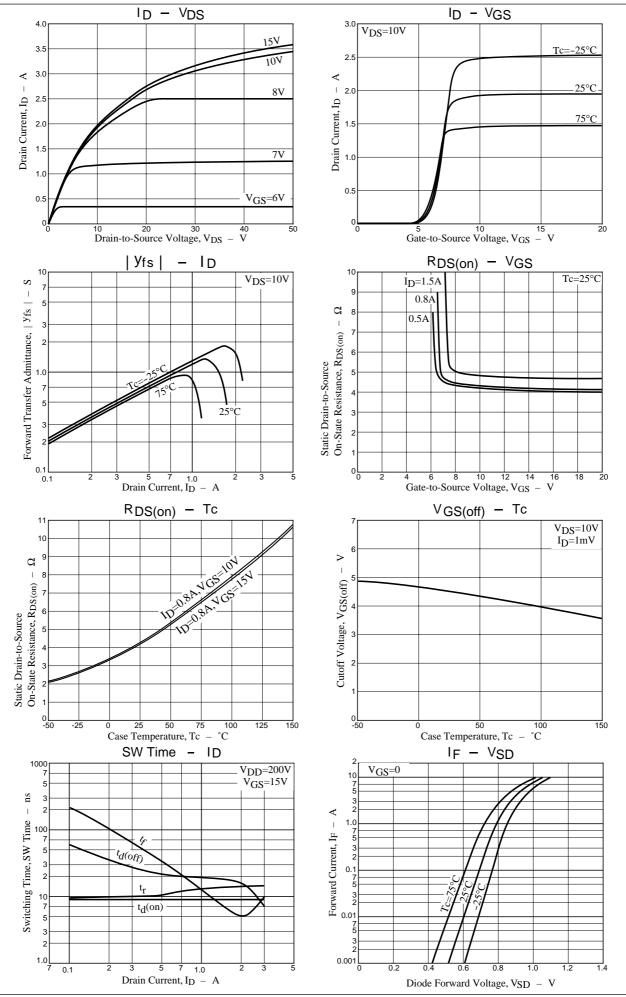
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	600			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =600V, V _{GS} =0			1.0	mA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±30V, V _{DS} =0			±100	nA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	3.5		5.5	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =0.8A	0.5	1.0		S
Static Drain-to-Source On-State Resistance	R _{DS(on)}	V _{GS} =15V, I _D =0.8A		4.2	5.5	Ω
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		300		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		90		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		45		pF
Total Gate Charge	Qg	V _{DS} =200V, V _{GS} =10V, I _D =1.5A		8		nC
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		9		ns
Rise Time	t _r	See specified Test Circuit		12		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		20		ns
Fall Time	t _f	See specified Test Circuit		17		ns
Diode Forward Voltage	V _{SD}	I _S =1.5A, V _{GS} =0		0.8	1.2	V

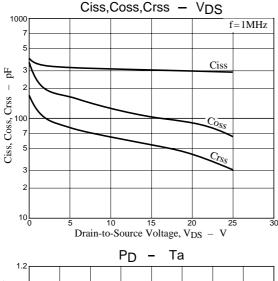
Marking: K2623

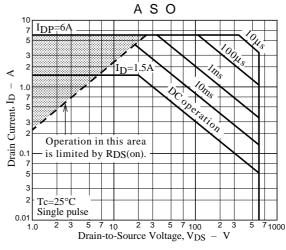
Switching Time Test Circuit

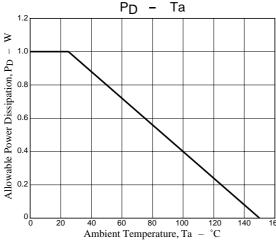


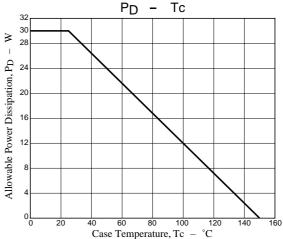


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